Supplementary Information

of

Enhanced Stability and Epitaxial Growth Mechanism of Honeycomb Borophene Monolayer on a Two-Dimensional Ti_2C Substrate

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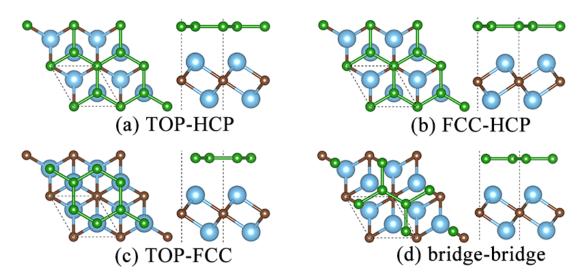


Figure S1. Initial structures of TOP-HCP (a), FCC-HCP (b), TOP-FCC (c) and bridge-bridge (d).

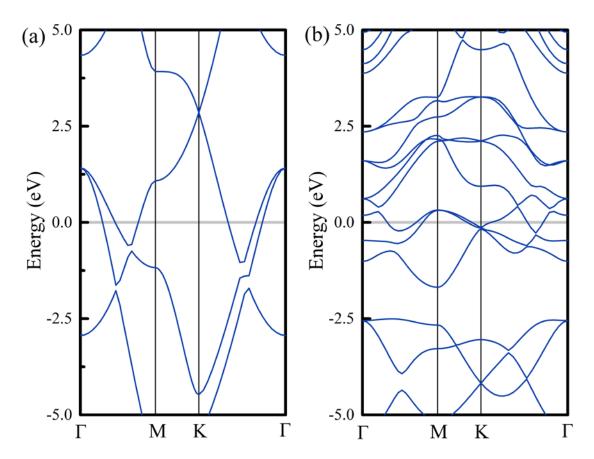


Figure S2. Band structures of free-standing honeycomb borophene (a) and Ti₂C (b), respectively.

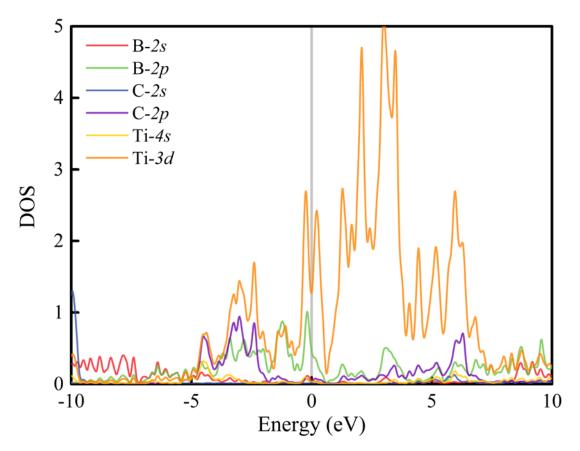


Figure S3. PDOS of borophene/Ti₂C system.